

■ 产品概述

XR8841(单通道)是低成本, 轨到轨输入/输出, 电压反馈放大器。它提供了宽的共模输入电压范围及输出电压摆幅, 其最低工作电压为 2.1V, 最高工作电压为 5.5V。其温度范围超出工业标准: -40°C 到 +125°C

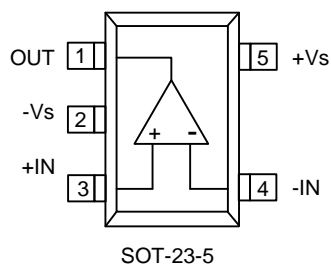
XR8841 能以 42 μ A/通道的低消耗电流提供高达 1.1M Hz 的带宽。其极低的偏置电流(0.5pA), 使它非常适合用在积分器、光电二极管放大器及压电式传感器等。轨到轨输入/输出的特性是设计专用集成电路的理想选择。

XR8841 可应用于多个领域, 如安全设备的监控、便携式设备、电池供电设备、信号处理、以及以低电源供电系统中传感器信号的处理等。

■ 用途

- ASIC 输入或输出放大器
- 音频输出
- 手持设备
- 移动电话
- 笔记本电脑
- PCMCIA 卡
- 电池供电设备

■ PIN 脚示意图



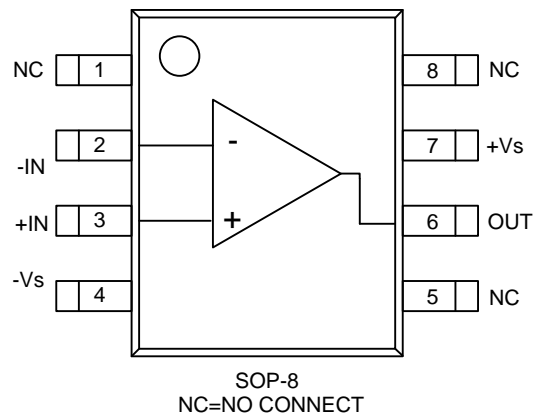
订购信息: **XR8841PR**

■ 产品特点

- 低成本
- 轨到轨输入/输出
- 单位增益稳定
- 压摆率: 0.52(V/ μ s)
- 最小电源抑制比: 72dB
- 最小共模抑制比: 76dB
- 失调电压: 典型值 0.8mV, 最大 3.5mV
- 增益带宽积: 1.1MHz
- 极低的输入偏置电流: 0.5pA
- 工作电压范围: 2.1V 到 5.5V
- 输入电压范围: 0.1V 到+5.6V ($V_S=5.5V$)
- 静态电流: 42 μ A

■ 封装

- SOP-8
- SOT-23-5



订购信息: **XR8841M**

■ 绝对最大额定值

项目	符号	值	单位
工作电压	V_{DD}	7.5	V
共模输入电压	V_{CM}	$(-V_S)-0.5$ 到 $(+V_S)+0.5$	V
贮存温度	T_{stg}	-55—150	°C
结点温度	—	150	°C
ESD 参数	HBM	4000	V
	MM	400	V

注意： 绝对最大额定值是指在任何条件下都不能超过的额定值。万一超过此额定值，有可能造成产品劣化等物理性损伤。

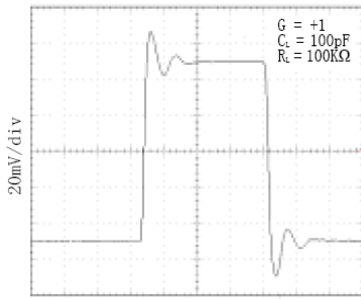
■ 电学特性参数

($V_S=+5V$ $R_L=100K\Omega$ $V_{OUT}=V_S/2$)

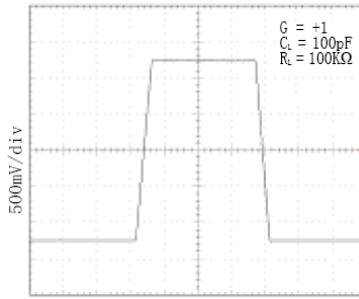
符号	参数	测试条件	最小	典型	最大	单位
V_{OS}	输入失调电压			± 0.8	± 5.4	mV
I_B	输入偏置电流			0.5		pA
I_{OS}	输入失调电流			0.5		pA
V_{CM}	共模电压范围	$V_S=5.5V$	-0.1		5.6	V
CMRR	共模抑制比	$V_S=5.5V$, $V_{CM}=-0.1V-4V$	72	88		dB
		$V_S=5.5V$, $V_{CM}=-0.1V-5.6V$	57	78		dB
A_{OL}	开环增益	$R_L=5K$, $V_O=0.1V-4.9V$	78	90		dB
		$R_L=100K$, $V_O=0.035V-4.965V$	82	94		dB
$\Delta V_{OS}/\Delta T$	输入失调电压温漂			2.7		$\mu V/^\circ C$
V_{SW}	输出电压到轨摆幅	$R_L=100K$		0.008		V
I_{OUT}	输出电流		18	23		mA
VDD	工作电压范围		2.1		5.5	
PSRR	电源抑制比	$V_S=+2.5V$ to $+5.5V$, $V_{CM}=(-V_S)+0.5V$	70	92		
I_Q	静态电流	$I_{OUT}=0$		42	60	μA
GBP	增益带宽积	$CL=100pF$		1.1		MHz
SR	压摆率			0.052		V/ μs

特征曲线

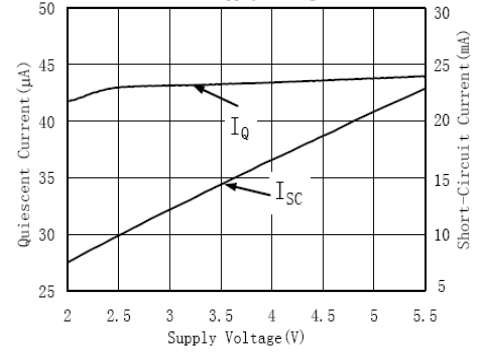
Small-Signal Step Response



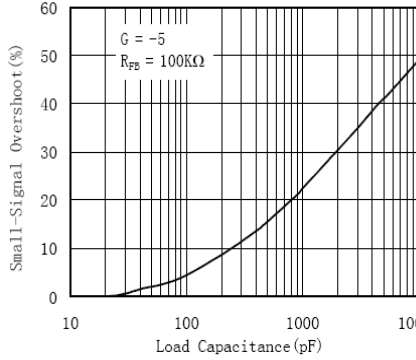
Large-Signal Step Response



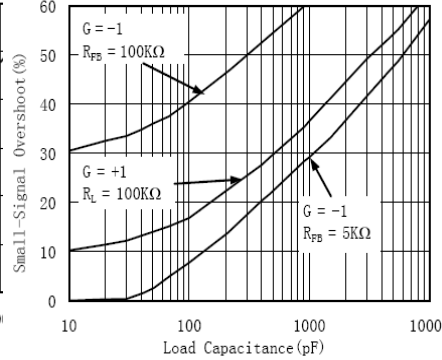
Quiescent And Short-Circuit Current vs. Supply Voltage



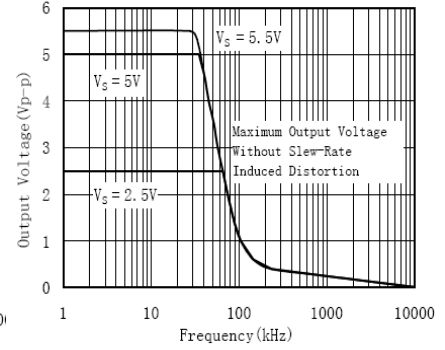
Small-Signal Overshoot vs. Load Capacitance



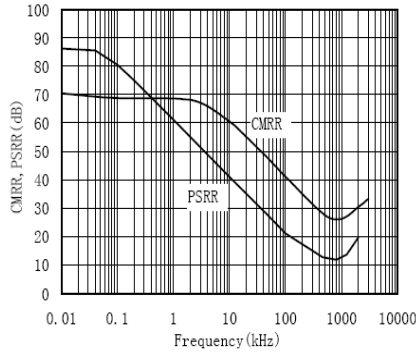
Small-Signal Overshoot vs. Load Capacitance



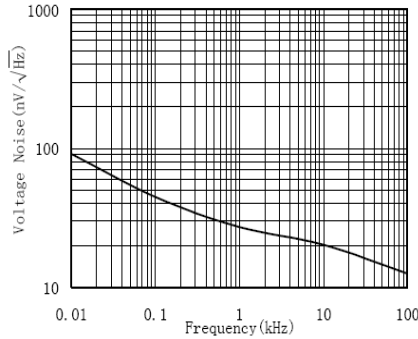
Maximum Output Voltage vs. Frequency



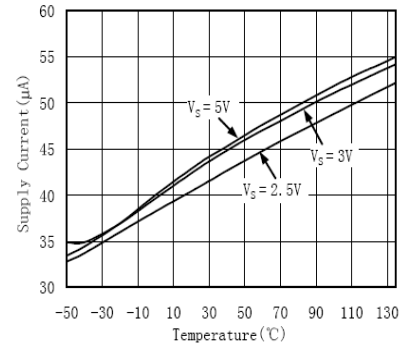
CMRR And PSRR vs. Frequency



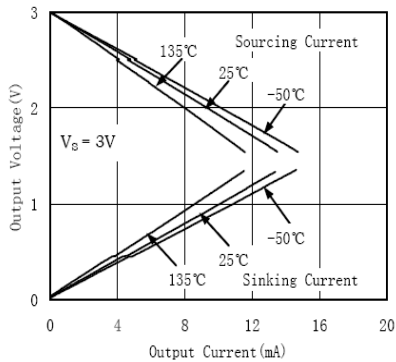
Input Voltage Noise Spectral Density vs. Frequency



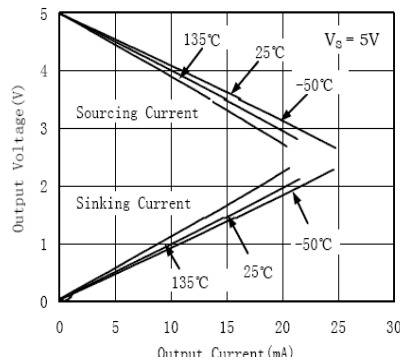
Supply Current vs. Temperature



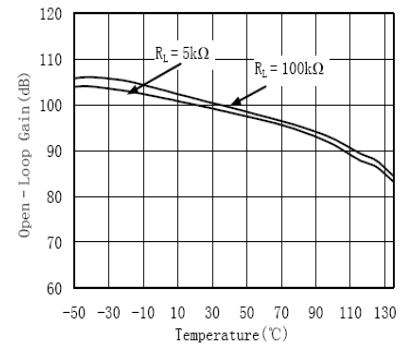
Output Voltage Swing vs. Output Current



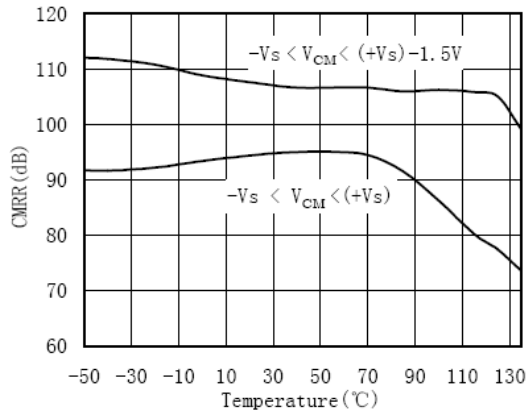
Output Voltage Swing vs. Output Current



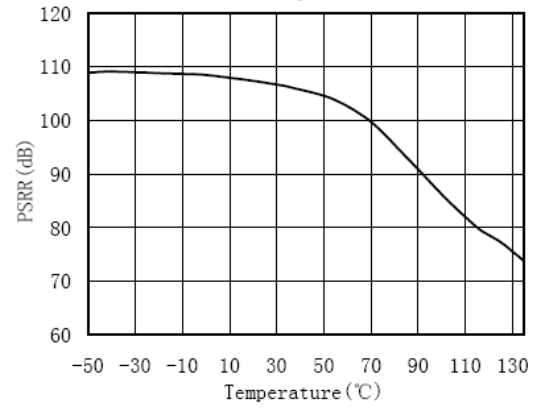
Open-Loop Gain vs. Temperature



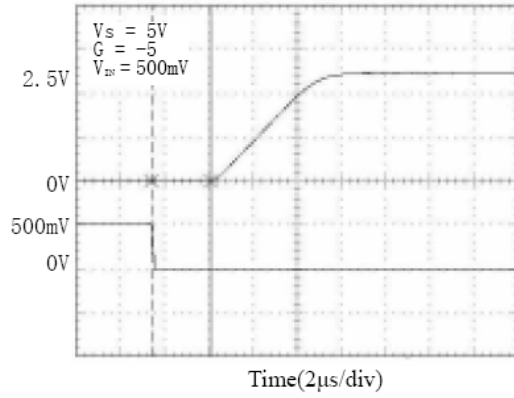
Common-Mode Rejection Ratio vs. Temperature



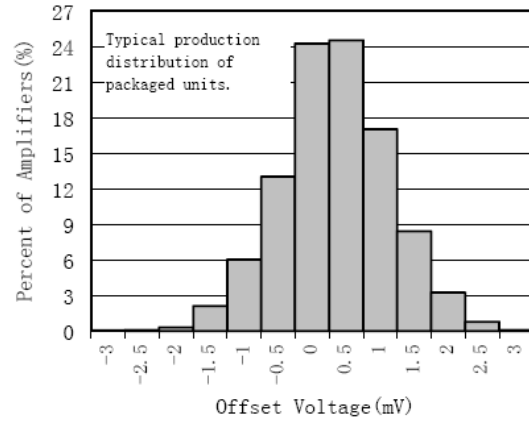
Power-Supply Rejection Ratio vs. Temperature



Overload Recovery Time

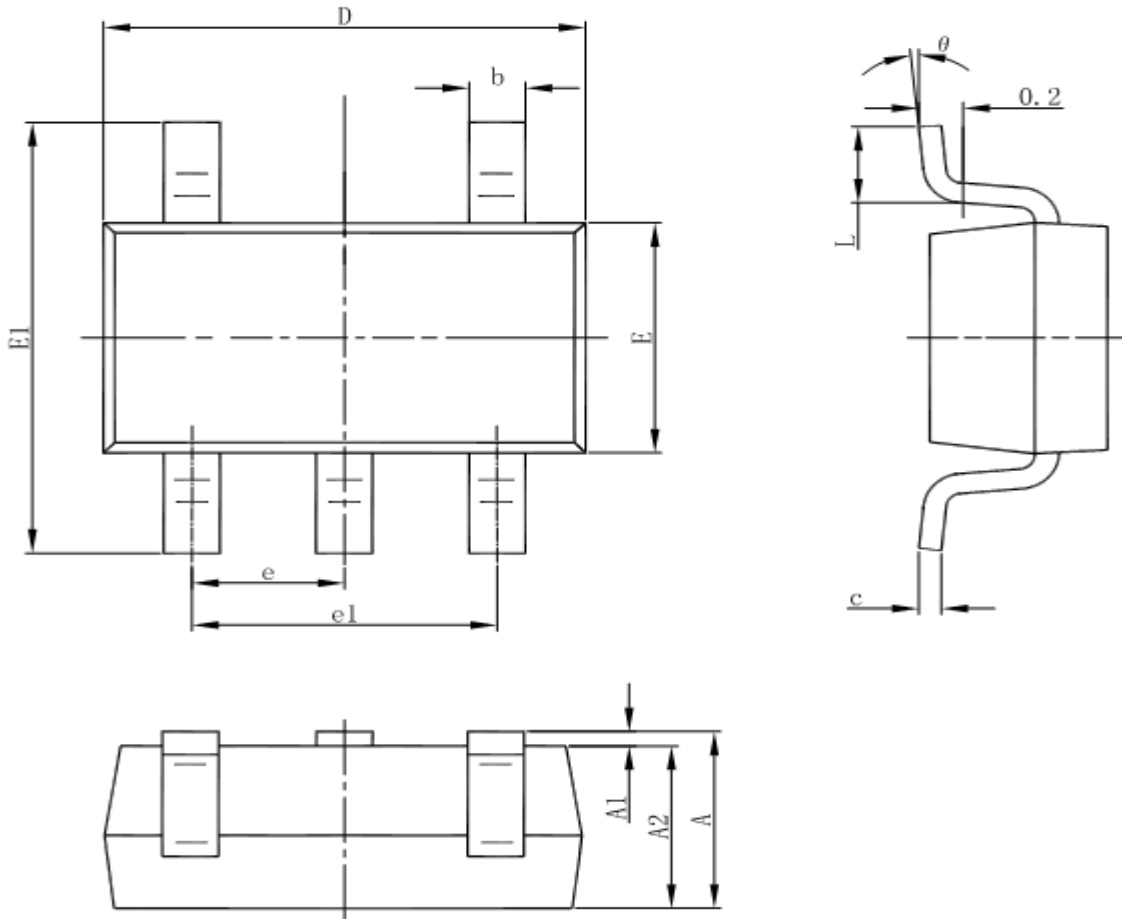


Offset Voltage Production Distribution



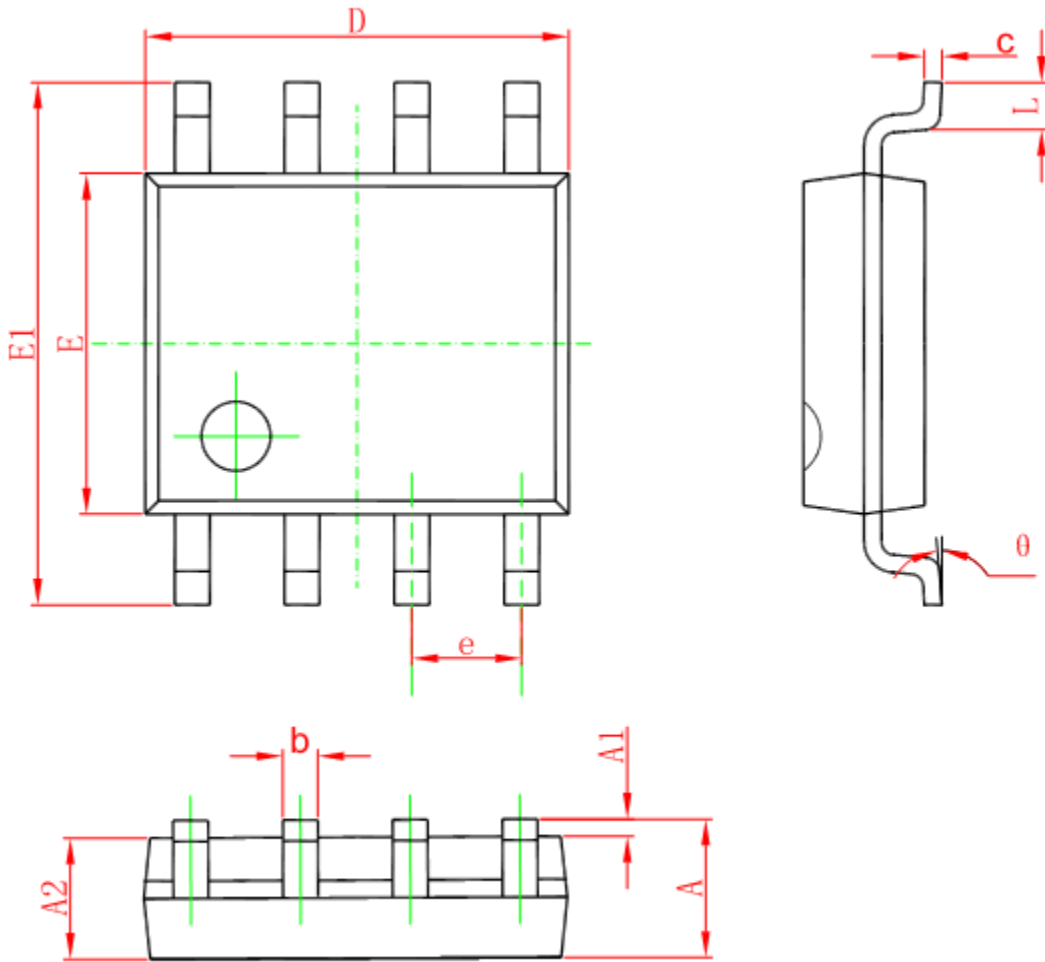
封装信息

- SOT-23-5



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

● SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°